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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Active |
| Core Processor | S08 |
| Core Size | 8-Bit |
| Speed | 20MHz |
| Connectivity | I ² C, LINbus, SPI, UART/USART |
| Peripherals | LVD, POR, PWM, WDT |
| Number of I/O | 37 |
| Program Memory Size | 16KB (16K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 256 x 8 |
| RAM Size | 2K x 8 |
| Voltage - Supply (Vcc/Vdd) | 2.7V ~ 5.5V |
| Data Converters | A/D 12x12b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 105°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 44-LQFP |
| Supplier Device Package | 44-LQFP (10x10) |
| Purchase URL | https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc9s08pt16vld |

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1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to freescale.com and perform a part number search for the following device numbers: PT16 and PT8.

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

MC 9 S08 PT AA (V) B CC

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

| Field | Description | Values |
|-------|------------------------------|--|
| MC | Qualification status | <ul style="list-style-type: none"> MC = fully qualified, general market flow |
| 9 | Memory | <ul style="list-style-type: none"> 9 = flash based |
| S08 | Core | <ul style="list-style-type: none"> S08 = 8-bit CPU |
| PT | Device family | <ul style="list-style-type: none"> PT |
| AA | Approximate flash size in KB | <ul style="list-style-type: none"> 16 = 16 KB 8 = 8 KB |
| (V) | Mask set version | <ul style="list-style-type: none"> (blank) = Any version A = Rev. 2 or later version, this is recommended for new design |

Table continues on the next page...

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either V_{SS} or V_{DD}) or the programmable pullup resistor associated with the pin is enabled.

| Symbol | Description | Min. | Max. | Unit |
|-----------|---|----------------|----------------|------|
| V_{DD} | Supply voltage | -0.3 | 6.0 | V |
| I_{DD} | Maximum current into V_{DD} | — | 120 | mA |
| V_{DIO} | Digital input voltage (except RESET, EXTAL, XTAL, or true open drain pin PTA2 and PTA3) | -0.3 | $V_{DD} + 0.3$ | V |
| | Digital input voltage (true open drain pin PTA2 and PTA3) | -0.3 | 6 | V |
| V_{AIO} | Analog ¹ , RESET, EXTAL, and XTAL input voltage | -0.3 | $V_{DD} + 0.3$ | V |
| I_D | Instantaneous maximum current single pin limit (applies to all port pins) | -25 | 25 | mA |
| V_{DDA} | Analog supply voltage | $V_{DD} - 0.3$ | $V_{DD} + 0.3$ | V |

1. All digital I/O pins, except open-drain pin PTA2 and PTA3, are internally clamped to V_{SS} and V_{DD} . PTA2 and PTA3 is only clamped to V_{SS} .

5 General

5.1 Nonswitching electrical specifications

5.1.1 DC characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 2. DC characteristics

| Symbol | C | Descriptions | | Min | Typical ¹ | Max | Unit |
|----------|---|---|---------------------------------------|---------------------------|----------------------|-----|------|
| — | — | Operating voltage | | 2.7 | — | 5.5 | V |
| V_{OH} | C | Output high voltage | All I/O pins, standard-drive strength | 5 V, $I_{load} = -5$ mA | $V_{DD} - 0.8$ | — | V |
| | C | | | 3 V, $I_{load} = -2.5$ mA | $V_{DD} - 0.8$ | — | V |
| | C | High current drive pins, high-drive strength ² | 5 V, $I_{load} = -20$ mA | $V_{DD} - 0.8$ | — | V | |
| | C | | 3 V, $I_{load} = -10$ mA | $V_{DD} - 0.8$ | — | V | |

Table continues on the next page...

Table 2. DC characteristics (continued)

| Symbol | C | Descriptions | | Min | Typical ¹ | Max | Unit | |
|------------------------------|---|---|--|--|------------------------|-----|------------------------|----|
| I _{OHT} | D | Output high current | Max total I _{OH} for all ports | 5 V | — | — | -100 | mA |
| | | | | 3 V | — | — | -50 | |
| V _{OL} | C | Output low voltage | All I/O pins, standard-drive strength | 5 V, I _{load} = 5 mA | — | — | 0.8 | V |
| | C | | | 3 V, I _{load} = 2.5 mA | — | — | 0.8 | V |
| | C | High current drive pins, high-drive strength ² | 5 V, I _{load} = 20 mA | — | — | 0.8 | V | |
| | C | | 3 V, I _{load} = 10 mA | — | — | 0.8 | V | |
| I _{OLT} | D | Output low current | Max total I _{OL} for all ports | 5 V | — | — | 100 | mA |
| | | | | 3 V | — | — | 50 | |
| V _{IH} | P | Input high voltage | All digital inputs | V _{DD} > 4.5V | 0.70 × V _{DD} | — | — | V |
| | C | | | V _{DD} > 2.7V | 0.75 × V _{DD} | — | — | |
| V _{IL} | P | Input low voltage | All digital inputs | V _{DD} > 4.5V | — | — | 0.30 × V _{DD} | V |
| | C | | | V _{DD} > 2.7V | — | — | 0.35 × V _{DD} | |
| V _{hys} | C | Input hysteresis | All digital inputs | — | 0.06 × V _{DD} | — | — | mV |
| I _{inI} | P | Input leakage current | All input only pins (per pin) | V _{IN} = V _{DD} or V _{SS} | — | 0.1 | 1 | μA |
| I _{oZI} | P | Hi-Z (off-state) leakage current | All input/output (per pin) | V _{IN} = V _{DD} or V _{SS} | — | 0.1 | 1 | μA |
| I _{oZTOTI} | C | Total leakage combined for all inputs and Hi-Z pins | All input only and I/O | V _{IN} = V _{DD} or V _{SS} | — | — | 2 | μA |
| R _{PU} | P | Pullup resistors | All digital inputs, when enabled (all I/O pins other than PTA2 and PTA3) | — | 30.0 | — | 50.0 | kΩ |
| R _{PU} ³ | P | Pullup resistors | PTA2 and PTA3 pin | — | 30.0 | — | 60.0 | kΩ |
| I _{IC} | D | DC injection current ^{4, 5, 6} | Single pin limit | V _{IN} < V _{SS} , V _{IN} > V _{DD} | -0.2 | — | 2 | mA |
| | | | Total MCU limit, includes sum of all stressed pins | | -5 | — | 25 | |
| C _{in} | C | Input capacitance, all pins | | — | — | — | 7 | pF |
| V _{RAM} | C | RAM retention voltage | | — | 2.0 | — | — | V |

1. Typical values are measured at 25 °C. Characterized, not tested.
2. Only PTB4, PTB5, PTD0, PTD1 support ultra high current output.
3. The specified resistor value is the actual value internal to the device. The pullup value may appear higher when measured externally on the pin.
4. All functional non-supply pins, except for PTA2 and PTA3, are internally clamped to V_{SS} and V_{DD}.
5. Input must be current-limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the large one.

6. Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If the positive injection current ($V_{in} > V_{DD}$) is higher than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure that external V_{DD} load will shunt current higher than maximum injection current when the MCU is not consuming power, such as no system clock is present, or clock rate is very low (which would reduce overall power consumption).

Table 3. LVD and POR Specification

| Symbol | C | Description | Min | Typ | Max | Unit | |
|--------------|---|---|-----------------------------|------|------|------|---|
| V_{POR} | D | POR re-arm voltage ^{1, 2} | 1.5 | 1.75 | 2.0 | V | |
| V_{LVDH} | C | Falling low-voltage detect threshold - high range (LVDV = 1) ³ | 4.2 | 4.3 | 4.4 | V | |
| V_{LVW1H} | C | Falling low-voltage warning threshold - high range | Level 1 falling (LVWV = 00) | 4.3 | 4.4 | 4.5 | V |
| V_{LVW2H} | C | | Level 2 falling (LVWV = 01) | 4.5 | 4.5 | 4.6 | V |
| V_{LVW3H} | C | | Level 3 falling (LVWV = 10) | 4.6 | 4.6 | 4.7 | V |
| V_{LVW4H} | C | | Level 4 falling (LVWV = 11) | 4.7 | 4.7 | 4.8 | V |
| V_{HYSH} | C | High range low-voltage detect/warning hysteresis | — | 100 | — | mV | |
| V_{LVDL} | C | Falling low-voltage detect threshold - low range (LVDV = 0) | 2.56 | 2.61 | 2.66 | V | |
| V_{LVDW1L} | C | Falling low-voltage warning threshold - low range | Level 1 falling (LVWV = 00) | 2.62 | 2.7 | 2.78 | V |
| V_{LVDW2L} | C | | Level 2 falling (LVWV = 01) | 2.72 | 2.8 | 2.88 | V |
| V_{LVDW3L} | C | | Level 3 falling (LVWV = 10) | 2.82 | 2.9 | 2.98 | V |
| V_{LVDW4L} | C | | Level 4 falling (LVWV = 11) | 2.92 | 3.0 | 3.08 | V |
| V_{HYSDL} | C | Low range low-voltage detect hysteresis | — | 40 | — | mV | |
| V_{HYSWL} | C | Low range low-voltage warning hysteresis | — | 80 | — | mV | |
| V_{BG} | P | Buffered bandgap output ⁴ | 1.14 | 1.16 | 1.18 | V | |

1. Maximum is highest voltage that POR is guaranteed.
2. POR ramp time must be longer than 20us/V to get a stable startup.
3. Rising thresholds are falling threshold + hysteresis.
4. Voltage factory trimmed at $V_{DD} = 5.0$ V, Temp = 25 °C

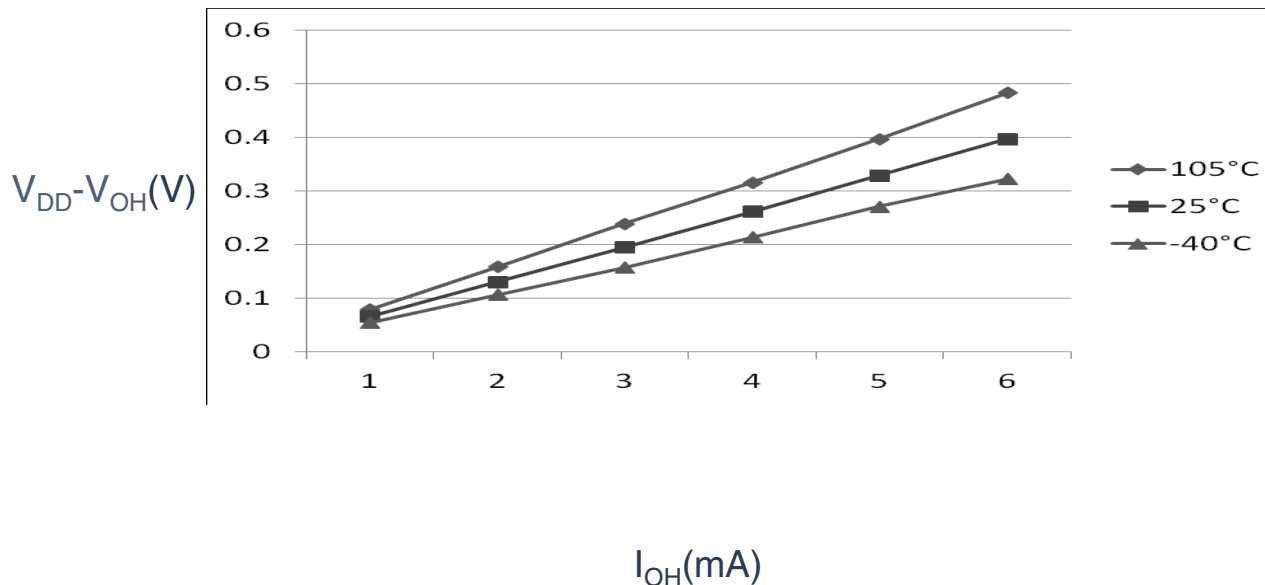


Figure 1. Typical I_{OH} Vs. $V_{DD}-V_{OH}$ (standard drive strength) ($V_{DD} = 5\text{ V}$)

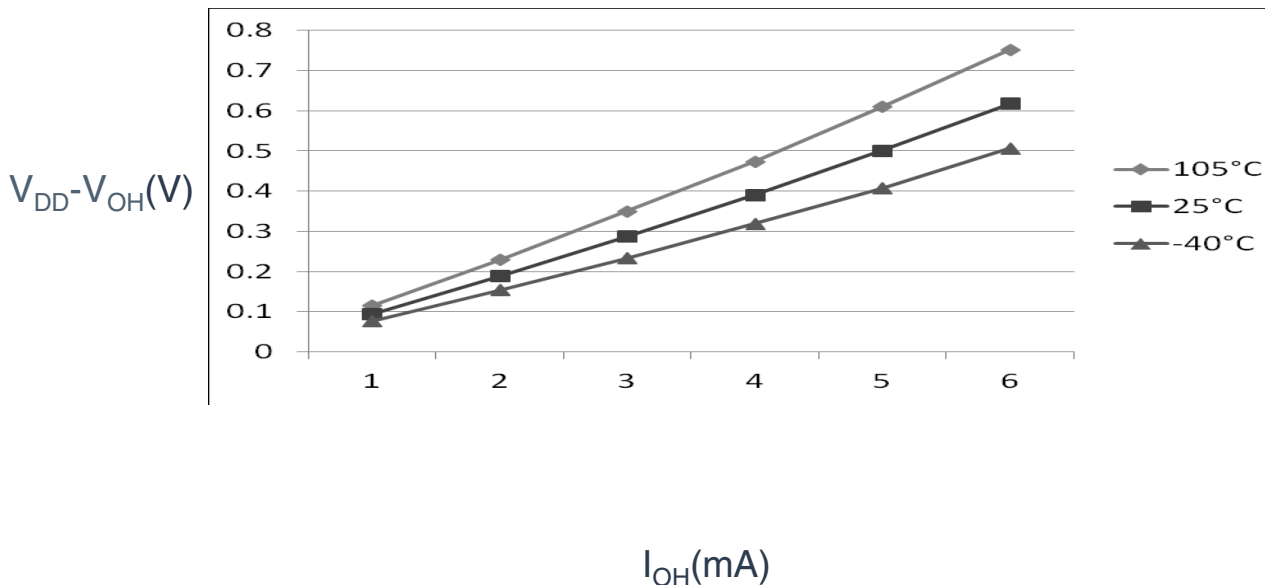


Figure 2. Typical I_{OH} Vs. $V_{DD}-V_{OH}$ (standard drive strength) ($V_{DD} = 3\text{ V}$)

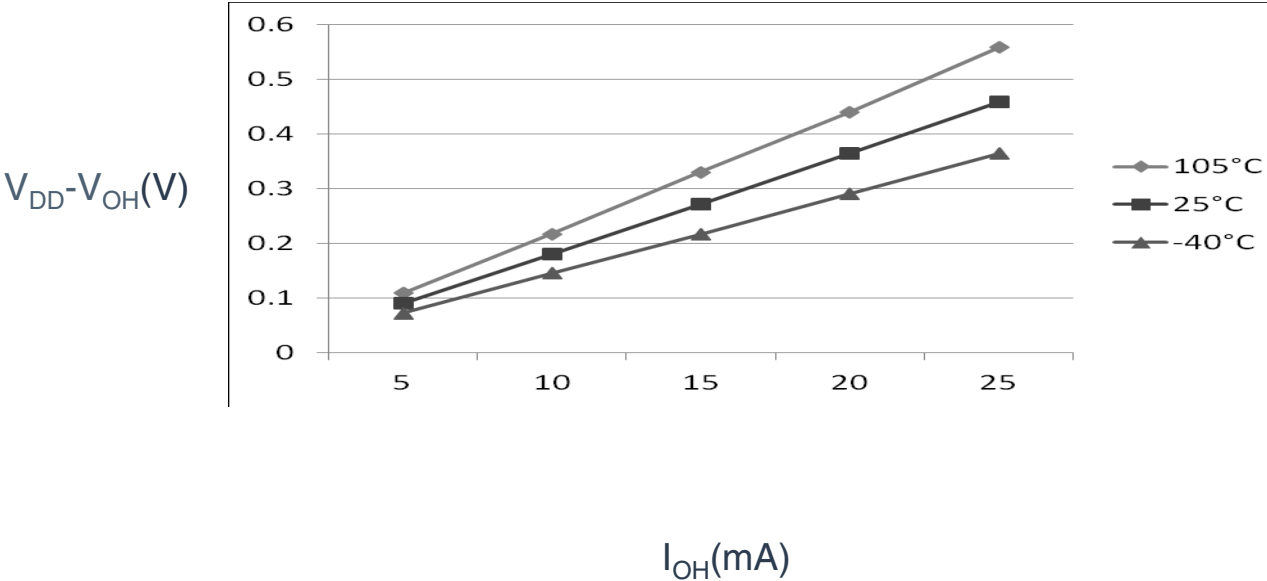


Figure 3. Typical I_{OH} Vs. $V_{DD}-V_{OH}$ (high drive strength) ($V_{DD} = 5\text{ V}$)

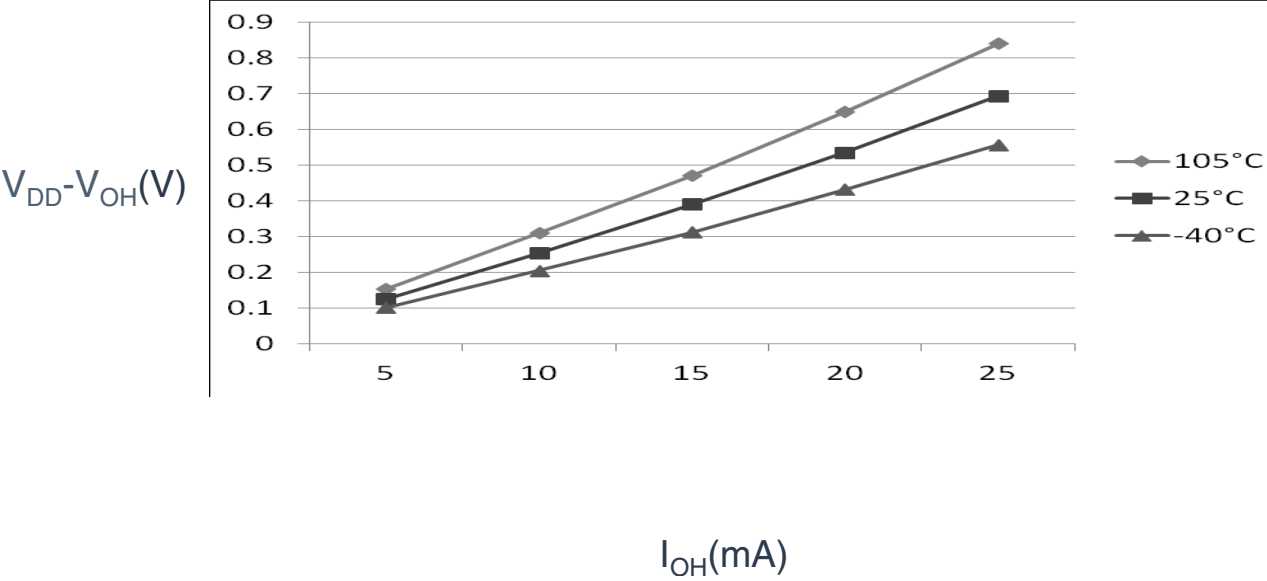


Figure 4. Typical I_{OH} Vs. $V_{DD}-V_{OH}$ (high drive strength) ($V_{DD} = 3\text{ V}$)

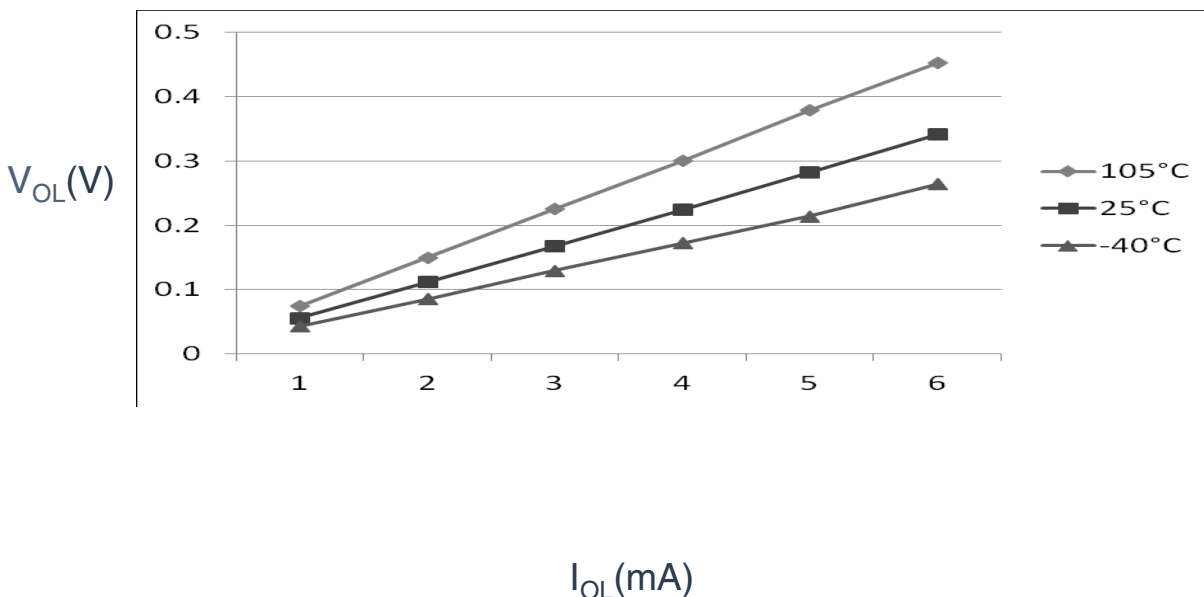


Figure 5. Typical I_{OL} Vs. V_{OL} (standard drive strength) ($V_{DD} = 5V$)

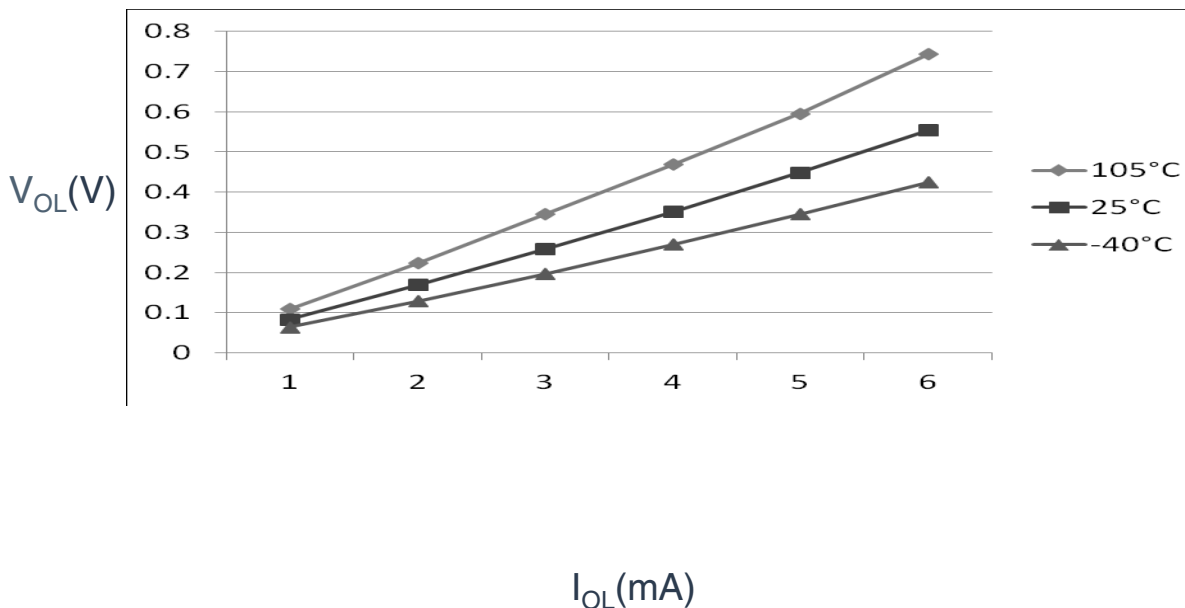


Figure 6. Typical I_{OL} Vs. V_{OL} (standard drive strength) ($V_{DD} = 3V$)

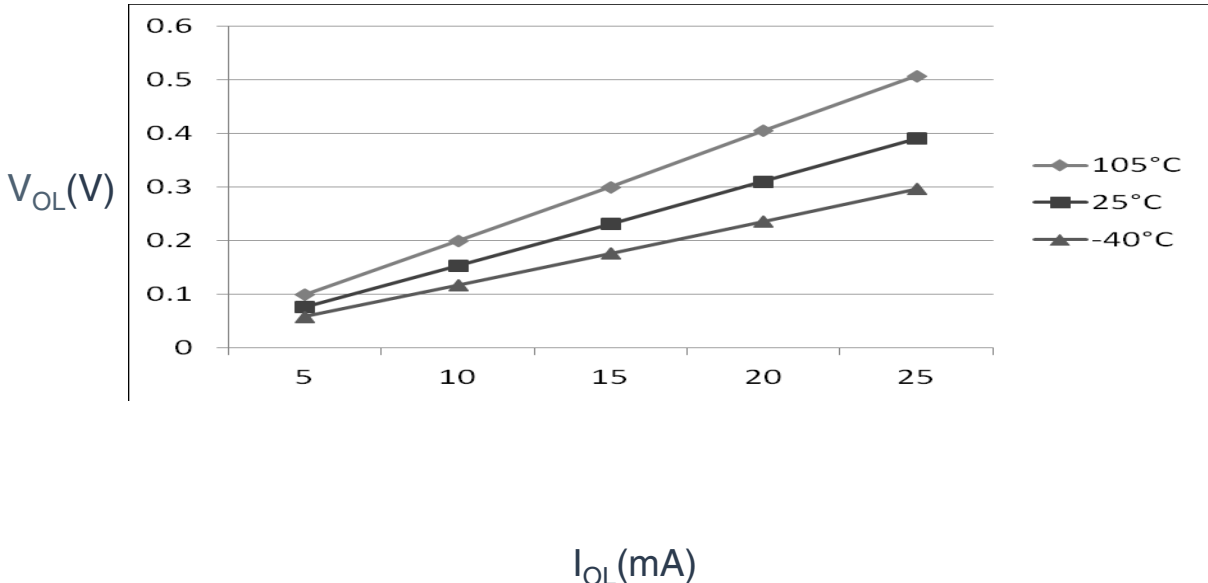


Figure 7. Typical I_{OL} Vs. V_{OL} (high drive strength) ($V_{DD} = 5\text{ V}$)

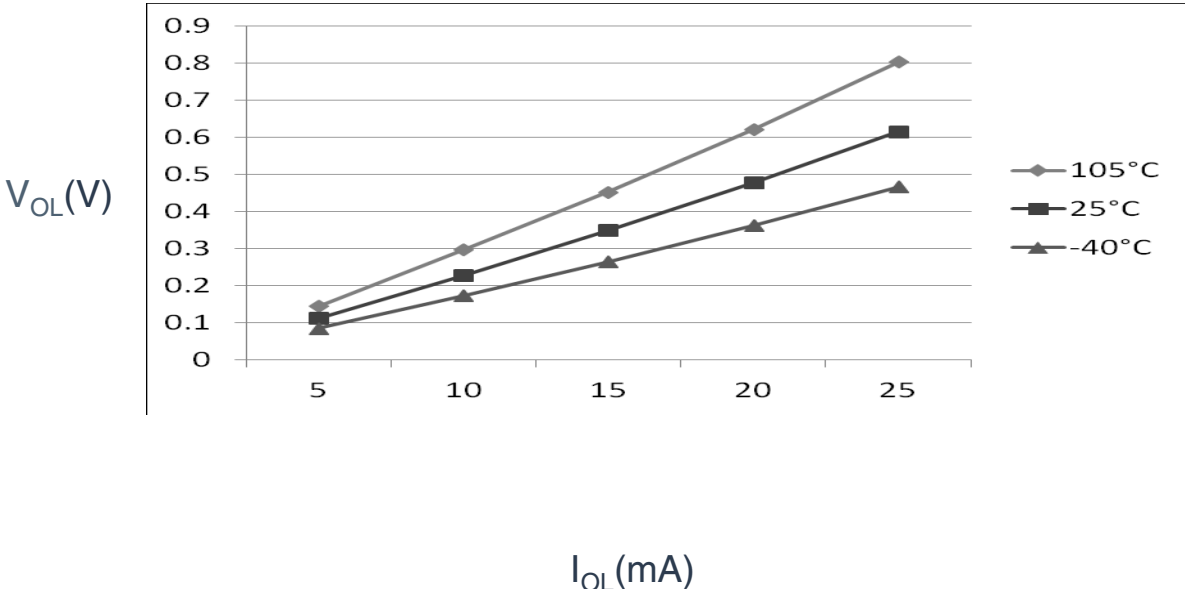


Figure 8. Typical I_{OL} Vs. V_{OL} (high drive strength) ($V_{DD} = 3\text{ V}$)

5.1.2 Supply current characteristics

This section includes information about power supply current in various operating modes.

Table 4. Supply current characteristics

| Num | C | Parameter | Symbol | Bus Freq | V _{DD} (V) | Typical ¹ | Max | Unit | Temp |
|-----|---|---|-------------------|----------|---------------------|----------------------|------|------|---------------|
| 1 | C | Run supply current FEI mode, all modules on; run from flash | RI _{DD} | 20 MHz | 5 | 7.60 | — | mA | -40 to 105 °C |
| | C | | | 10 MHz | | 4.65 | — | | |
| | C | | | 1 MHz | | 1.90 | — | | |
| | C | | | 20 MHz | 3 | 7.05 | — | | |
| | C | | | 10 MHz | | 4.40 | — | | |
| | C | | | 1 MHz | | 1.85 | — | | |
| 2 | C | Run supply current FEI mode, all modules off & gated; run from flash | RI _{DD} | 20 MHz | 5 | 5.88 | — | mA | -40 to 105 °C |
| | C | | | 10 MHz | | 3.70 | — | | |
| | C | | | 1 MHz | | 1.85 | — | | |
| | C | | | 20 MHz | 3 | 5.35 | — | | |
| | C | | | 10 MHz | | 3.42 | — | | |
| | C | | | 1 MHz | | 1.80 | — | | |
| 3 | P | Run supply current FBE mode, all modules on; run from RAM | RI _{DD} | 20 MHz | 5 | 10.9 | 14.0 | mA | -40 to 105 °C |
| | C | | | 10 MHz | | 6.10 | — | | |
| | C | | | 1 MHz | | 1.69 | — | | |
| | C | | | 20 MHz | 3 | 8.18 | — | | |
| | C | | | 10 MHz | | 5.14 | — | | |
| | C | | | 1 MHz | | 1.44 | — | | |
| 4 | P | Run supply current FBE mode, all modules off & gated; run from RAM | RI _{DD} | 20 MHz | 5 | 8.50 | 13.0 | mA | -40 to 105 °C |
| | C | | | 10 MHz | | 5.07 | — | | |
| | C | | | 1 MHz | | 1.59 | — | | |
| | C | | | 20 MHz | 3 | 6.11 | — | | |
| | C | | | 10 MHz | | 4.10 | — | | |
| | C | | | 1 MHz | | 1.34 | — | | |
| 5 | C | Wait mode current FEI mode, all modules on | WI _{DD} | 20 MHz | 5 | 5.95 | — | mA | -40 to 105 °C |
| | C | | | 10 MHz | | 3.50 | — | | |
| | C | | | 1 MHz | | 1.24 | — | | |
| | C | | | 20 MHz | 3 | 5.45 | — | | |
| | C | | | 10 MHz | | 3.25 | — | | |
| | C | | | 1 MHz | | 1.20 | — | | |
| 6 | C | Stop3 mode supply current no clocks active (except 1kHz LPO clock) ^{2,3} | S3I _{DD} | — | 5 | 4.6 | — | μA | -40 to 105 °C |
| | C | | | — | 3 | 4.5 | — | | -40 to 105 °C |
| 7 | C | ADC adder to stop3 | — | — | 5 | 40 | — | μA | -40 to 105 °C |

Table continues on the next page...

Table 4. Supply current characteristics (continued)

| Num | C | Parameter | Symbol | Bus Freq | V _{DD} (V) | Typical ¹ | Max | Unit | Temp |
|-----|---|---|--------|----------|---------------------|----------------------|-----|------|---------------|
| | C | ADLPC = 1 ADLSMP = 1 ADCO = 1 MODE = 10B ADICLK = 11B | | | 3 | 39 | — | | |
| 8 | C | TSI adder to stop3 ⁴ | — | — | 5 | 121 | — | μA | -40 to 105 °C |
| | C | PS = 010B NSCN = 0x0F EXTCHRG = 0 REFCHRG = 0 DVOLT = 01B | | | 3 | 120 | — | | |
| 9 | C | LVD adder to stop3 ⁵ | — | — | 5 | 128 | — | μA | -40 to 105 °C |
| | C | | | | 3 | 124 | — | | |

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. RTC adder cause <1 μA I_{DD} increase typically, RTC clock source is 1kHz LPO clock.
3. ACMP adder cause <10 μA I_{DD} increase typically.
4. The current varies with TSI configuration and capacity of touch electrode. Please refer to [TSI electrical specifications](#).
5. LVD is periodically woken up from stop3 by 5% duty cycle. The period is equal to or less than 2 ms.

5.1.3 EMC performance

Electromagnetic compatibility (EMC) performance is highly dependent on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation all play a significant role in EMC performance. The system designer should consult Freescale applications notes such as [AN2321](#), [AN1050](#), [AN1263](#), [AN2764](#), and [AN1259](#) for advice and guidance specifically targeted at optimizing EMC performance.

5.1.3.1 EMC radiated emissions operating behaviors

Table 5. EMC radiated emissions operating behaviors for 44-pin LQFP package

| Symbol | Description | Frequency band (MHz) | Typ. | Unit | Notes |
|---------------------|------------------------------------|----------------------|------|------|-------|
| V _{RE1} | Radiated emissions voltage, band 1 | 0.15–50 | 8 | dBμV | 1, 2 |
| V _{RE2} | Radiated emissions voltage, band 2 | 50–150 | 8 | dBμV | |
| V _{RE3} | Radiated emissions voltage, band 3 | 150–500 | 8 | dBμV | |
| V _{RE4} | Radiated emissions voltage, band 4 | 500–1000 | 5 | dBμV | |
| V _{RE_IEC} | IEC level | 0.15–1000 | N | — | 2, 3 |

Switching specifications

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2. $V_{DD} = 5.0\text{ V}$, $T_A = 25\text{ °C}$, $f_{OSC} = 10\text{ MHz}$ (crystal), $f_{SYS} = 20\text{ MHz}$, $f_{BUS} = 20\text{ MHz}$
3. Specified according to Annex D of IEC Standard 61967-2, *Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*

5.2 Switching specifications

5.2.1 Control timing

Table 6. Control timing

| Num | C | Rating | Symbol | Min | Typical ¹ | Max | Unit |
|-----|---|--|--------------------------------|----------------------|----------------------|------|------|
| 1 | P | Bus frequency ($t_{cyc} = 1/f_{Bus}$) | f_{Bus} | DC | — | 20 | MHz |
| 2 | C | Internal low power oscillator frequency | f_{LPO} | — | 1.0 | — | KHz |
| 3 | D | External reset pulse width ² | t_{extrst} | $1.5 \times t_{cyc}$ | — | — | ns |
| 4 | D | Reset low drive | t_{rstdrv} | $34 \times t_{cyc}$ | — | — | ns |
| 5 | D | BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes | t_{MSSU} | 500 | — | — | ns |
| 6 | D | BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes ³ | t_{MSH} | 100 | — | — | ns |
| 7 | D | IRQ pulse width | Asynchronous path ² | t_{LIH} | 100 | — | ns |
| | D | | Synchronous path ⁴ | t_{HIL} | $1.5 \times t_{cyc}$ | — | ns |
| 8 | D | Keyboard interrupt pulse width | Asynchronous path ² | t_{LIH} | 100 | — | ns |
| | D | | Synchronous path | t_{HIL} | $1.5 \times t_{cyc}$ | — | ns |
| 9 | C | Port rise and fall time - standard drive strength (load = 50 pF) ⁵ | — | t_{Rise} | — | 10.2 | ns |
| | C | | — | t_{Fall} | — | 9.5 | ns |
| | C | Port rise and fall time - high drive strength (load = 50 pF) ⁵ | — | t_{Rise} | — | 5.4 | ns |
| | C | | — | t_{Fall} | — | 4.6 | ns |

1. Typical values are based on characterization data at $V_{DD} = 5.0\text{ V}$, 25 °C unless otherwise stated.
2. This is the shortest pulse that is guaranteed to be recognized as a reset pin request.
3. To enter BDM mode following a POR, BKGD/MS must be held low during the powerup and for a hold time of t_{MSH} after V_{DD} rises above V_{LVD} .
4. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized.
5. Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range -40 °C to 105 °C .

5.3 Thermal specifications

5.3.1 Thermal characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 9. Thermal characteristics

| Rating | Symbol | Value | Unit |
|--|--------------------|---------------------------|------|
| Operating temperature range (packaged) | T_A ¹ | T_L to T_H -40 to 105 | °C |
| Junction temperature range | T_J | -40 to 150 | °C |
| Thermal resistance single-layer board | | | |
| 44-pin LQFP | $R_{\theta JA}$ | 76 | °C/W |
| 32-pin LQFP | $R_{\theta JA}$ | 88 | °C/W |
| 20-pin SOIC | $R_{\theta JA}$ | 82 | °C/W |
| 20-pin TSSOP | $R_{\theta JA}$ | 116 | °C/W |
| 16-pin TSSOP | $R_{\theta JA}$ | 130 | °C/W |
| Thermal resistance four-layer board | | | |
| 44-pin LQFP | $R_{\theta JA}$ | 54 | °C/W |
| 32-pin LQFP | $R_{\theta JA}$ | 59 | °C/W |
| 20-pin SOIC | $R_{\theta JA}$ | 54 | °C/W |
| 20-pin TSSOP | $R_{\theta JA}$ | 76 | °C/W |
| 16-pin TSSOP | $R_{\theta JA}$ | 87 | °C/W |

- Maximum T_A can be exceeded only if the user ensures that T_J does not exceed the maximum. The simplest method to determine T_J is: $T_J = T_A + R_{\theta JA} \times \text{chip power dissipation}$.

6 Peripheral operating requirements and behaviors

6.3 Analog

6.3.1 ADC characteristics

Table 12. 5 V 12-bit ADC operating conditions

| Characteristic | Conditions | Symb | Min | Typ ¹ | Max | Unit | Comment |
|---------------------------------------|---|------------------|------------|------------------|-----------------|------------|-----------------|
| Supply voltage | Absolute | V_{DDA} | 2.7 | — | 5.5 | V | — |
| | Delta to V_{DD} ($V_{DD}-V_{DDAD}$) | ΔV_{DDA} | -100 | 0 | +100 | mV | |
| Ground voltage | Delta to V_{SS} ($V_{SS}-V_{SSA}$) ² | ΔV_{SSA} | -100 | 0 | +100 | mV | |
| Input voltage | | V_{ADIN} | V_{REFL} | — | V_{REFH} | V | |
| Input capacitance | | C_{ADIN} | — | 4.5 | 5.5 | pF | |
| Input resistance | | R_{ADIN} | — | 3 | 5 | k Ω | — |
| Analog source resistance | 12-bit mode | R_{AS} | — | — | 2 | k Ω | External to MCU |
| | • $f_{ADCK} > 4$ MHz | | — | — | 5 | | |
| | • $f_{ADCK} < 4$ MHz | | — | — | 5 | | |
| 10-bit mode | — | — | 5 | k Ω | External to MCU | | |
| • $f_{ADCK} > 4$ MHz | — | — | 10 | | | | |
| • $f_{ADCK} < 4$ MHz | — | — | 10 | | | | |
| 8-bit mode (all valid f_{ADCK}) | | | | | | | |
| ADC conversion clock frequency | High speed (ADLPC=0) | f_{ADCK} | 0.4 | — | 8.0 | MHz | — |
| | Low power (ADLPC=1) | | 0.4 | — | 4.0 | | |

1. Typical values assume $V_{DDA} = 5.0$ V, Temp = 25°C, $f_{ADCK}=1.0$ MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. DC potential difference.

6.3.2 Analog comparator (ACMP) electricals

Table 14. Comparator electrical specifications

| C | Characteristic | Symbol | Min | Typical | Max | Unit |
|---|---------------------------------------|---------------------|----------------|---------|-----------|---------------|
| D | Supply voltage | V_{DDA} | 2.7 | — | 5.5 | V |
| T | Supply current (Operation mode) | I_{DDA} | — | 10 | 20 | μA |
| D | Analog input voltage | V_{AIN} | $V_{SS} - 0.3$ | — | V_{DDA} | V |
| P | Analog input offset voltage | V_{AIO} | — | — | 40 | mV |
| C | Analog comparator hysteresis (HYST=0) | V_H | — | 15 | 20 | mV |
| C | Analog comparator hysteresis (HYST=1) | V_H | — | 20 | 30 | mV |
| T | Supply current (Off mode) | $I_{DDA\text{OFF}}$ | — | 60 | — | nA |
| C | Propagation Delay | t_D | — | 0.4 | 1 | μs |

6.4 Communication interfaces

6.4.1 SPI switching specifications

The serial peripheral interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. Refer to the SPI chapter of the chip's reference manual for information about the modified transfer formats used for communicating with slower peripheral devices. All timing is shown with respect to 20% V_{DD} and 70% V_{DD} , unless noted, and 100 pF load on all SPI pins. All timing assumes high drive strength is enabled for SPI output pins.

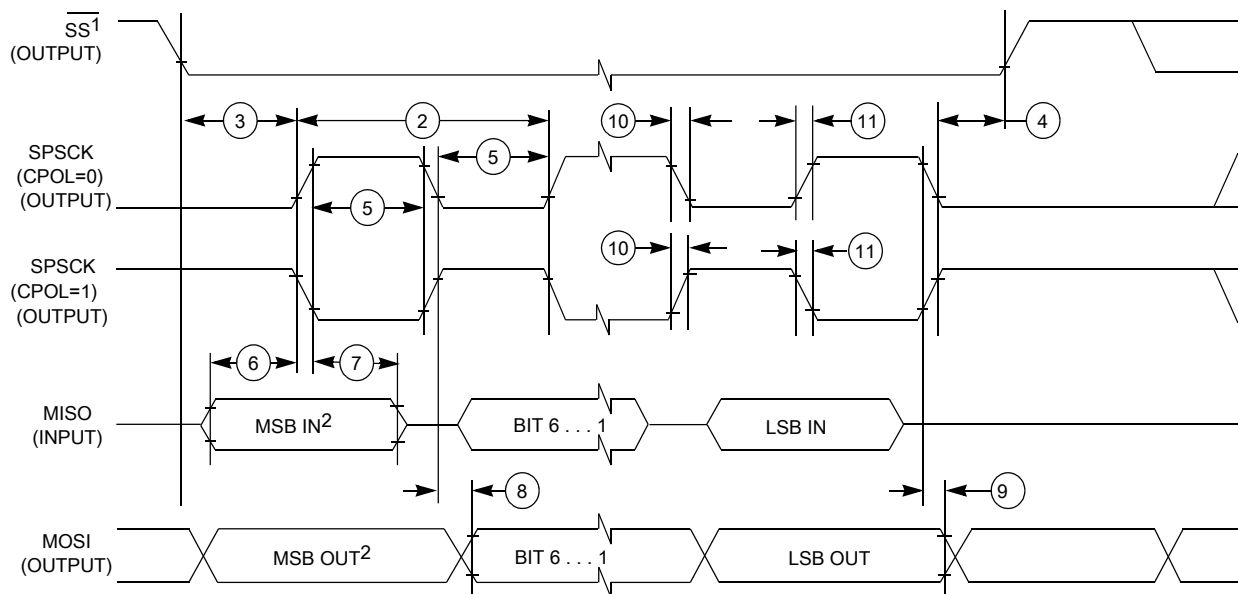
Table 15. SPI master mode timing

| Num. | Symbol | Description | Min. | Max. | Unit | Comment |
|------|--------------|--------------------------------|--------------------|-----------------------|-------------|----------------------------|
| 1 | f_{op} | Frequency of operation | $f_{Bus}/2048$ | $f_{Bus}/2$ | Hz | f_{Bus} is the bus clock |
| 2 | t_{SPSCK} | SPSCK period | $2 \times t_{Bus}$ | $2048 \times t_{Bus}$ | ns | $t_{Bus} = 1/f_{Bus}$ |
| 3 | t_{Lead} | Enable lead time | 1/2 | — | t_{SPSCK} | — |
| 4 | t_{Lag} | Enable lag time | 1/2 | — | t_{SPSCK} | — |
| 5 | t_{WSPSCK} | Clock (SPSCK) high or low time | $t_{Bus} - 30$ | $1024 \times t_{Bus}$ | ns | — |
| 6 | t_{SU} | Data setup time (inputs) | 15 | — | ns | — |
| 7 | t_{HI} | Data hold time (inputs) | 0 | — | ns | — |
| 8 | t_v | Data valid (after SPSCK edge) | — | 25 | ns | — |
| 9 | t_{HO} | Data hold time (outputs) | 0 | — | ns | — |
| 10 | t_{RI} | Rise time input | — | $t_{Bus} - 25$ | ns | — |

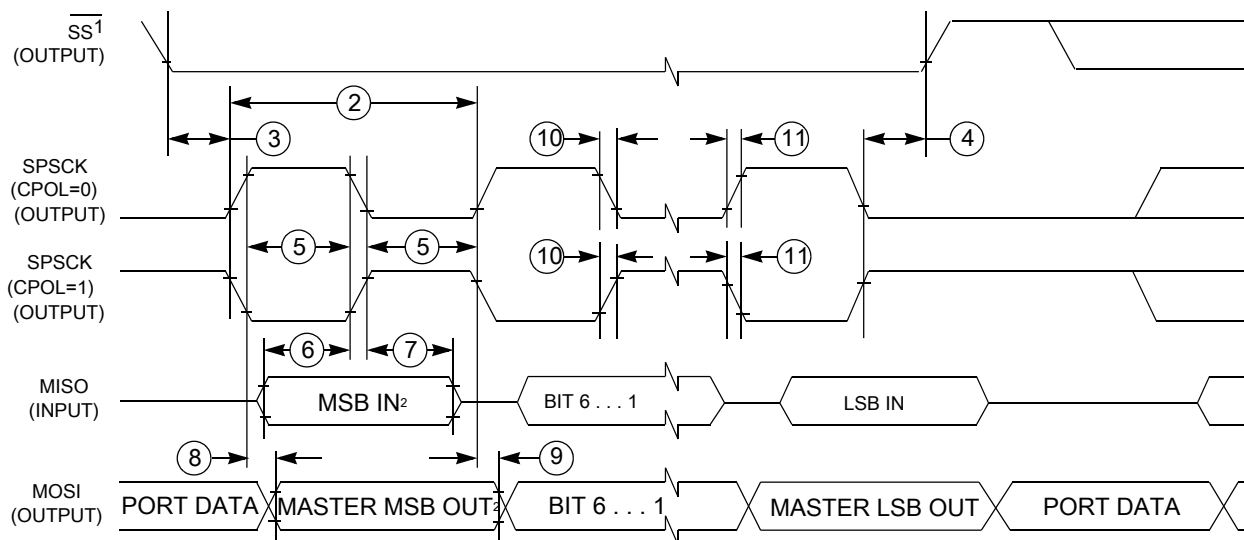
Table continues on the next page...

Table 15. SPI master mode timing (continued)

| Nu m. | Symbol | Description | Min. | Max. | Unit | Comment |
|-------|----------|------------------|------|------|------|---------|
| | t_{FI} | Fall time input | | | | |
| 11 | t_{RO} | Rise time output | — | 25 | ns | — |
| | t_{FO} | Fall time output | | | | |



1. If configured as an output.
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 17. SPI master mode timing (CPHA=0)


1. If configured as output
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 18. SPI master mode timing (CPHA=1)

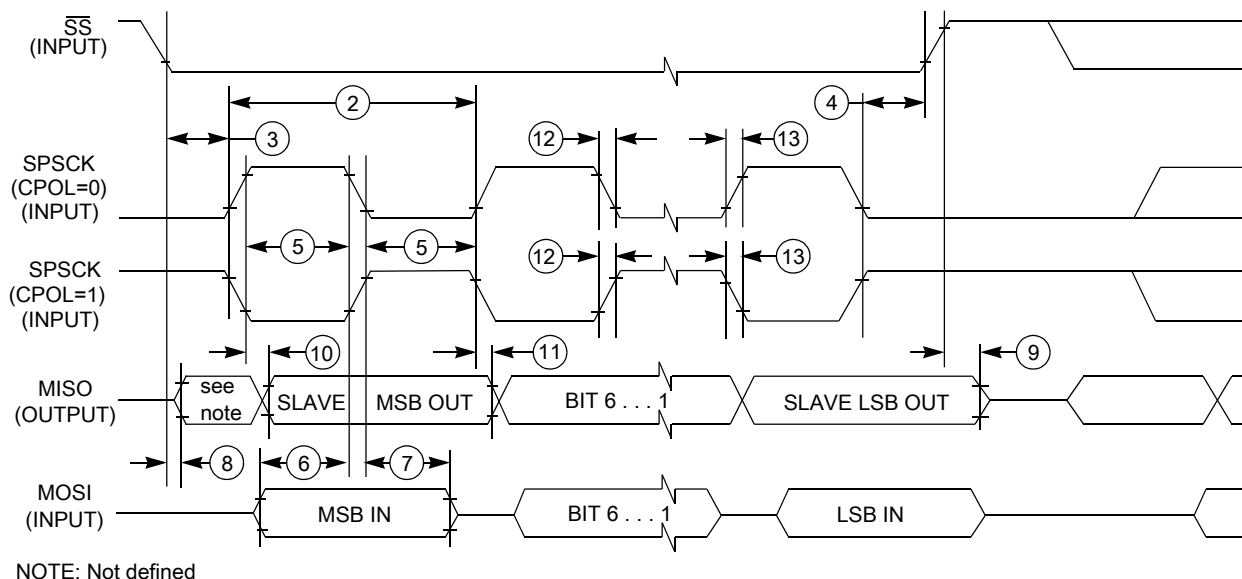


Figure 20. SPI slave mode timing (CPHA=1)

6.5 Human-machine interfaces (HMI)

6.5.1 TSI electrical specifications

Table 17. TSI electrical specifications

| Symbol | Description | Min. | Type | Max | Unit |
|-----------|--|------|------|-----|------|
| TSI_RUNF | Fixed power consumption in run mode | — | 100 | — | μA |
| TSI_RUNV | Variable power consumption in run mode (depends on oscillator's current selection) | 1.0 | — | 128 | μA |
| TSI_EN | Power consumption in enable mode | — | 100 | — | μA |
| TSI_DIS | Power consumption in disable mode | — | 1.2 | — | μA |
| TSI_TEN | TSI analog enable time | — | 66 | — | μs |
| TSI_CREF | TSI reference capacitor | — | 1.0 | — | pF |
| TSI_DVOLT | Voltage variation of VP & VM around nominal values | -10 | — | 10 | % |

7 Dimensions

7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to freescale.com and perform a keyword search for the drawing's document number:

| If you want the drawing for this package | Then use this document number |
|--|-------------------------------|
| 16-pin TSSOP | 98ASH70247A |
| 20-pin SOIC | 98ASB42343B |
| 20-pin TSSOP | 98ASH70169A |
| 32-pin LQFP | 98ASH70029A |
| 44-pin LQFP | 98ASS23225W |

8 Pinout

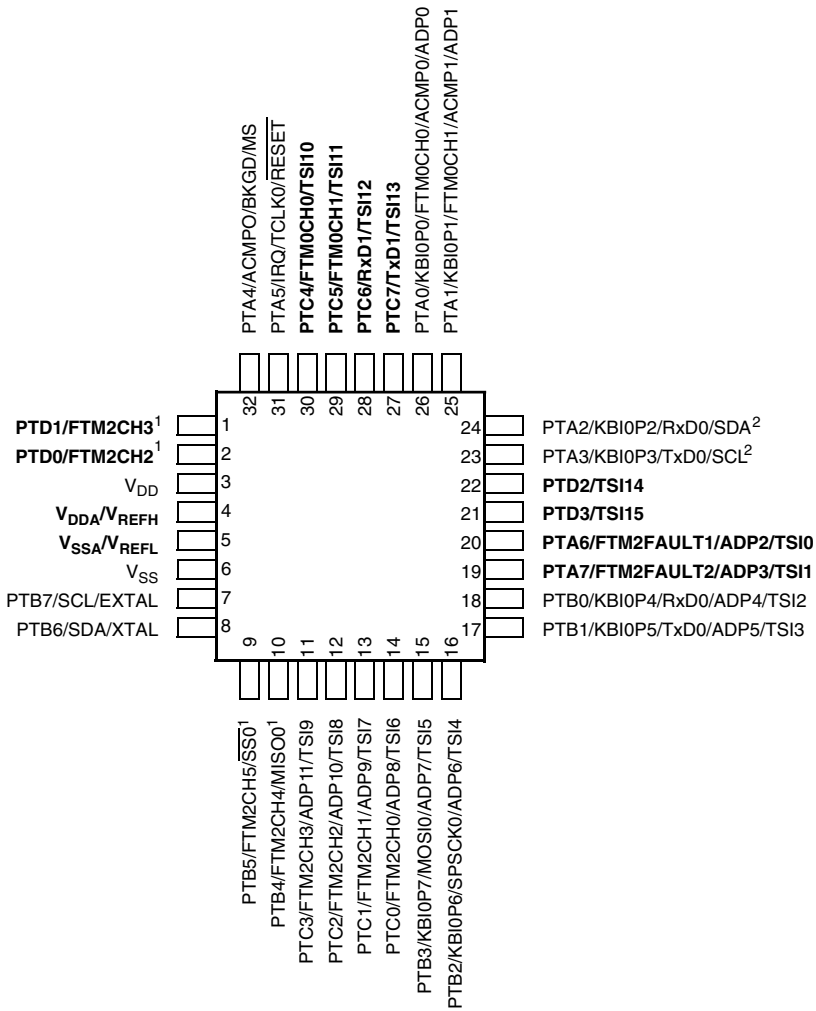
8.1 Signal multiplexing and pin assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

Table 18. Pin availability by package pin-count

| Pin Number | | | | Lowest Priority <-- --> Highest | | | | |
|------------|---------|----------|----------|---------------------------------|-------|---------|------------------|-------------------|
| 44-LQFP | 32-LQFP | 20-TSSOP | 16-TSSOP | Port Pin | Alt 1 | Alt 2 | Alt 3 | Alt 4 |
| 1 | 1 | — | — | PTD1 ¹ | — | FTM2CH3 | — | — |
| 2 | 2 | — | — | PTD0 ¹ | — | FTM2CH2 | — | — |
| 3 | — | — | — | PTE4 | — | TCLK2 | — | — |
| 4 | — | — | — | PTE3 | — | BUSOUT | — | — |
| 5 | 3 | 3 | 3 | — | — | — | — | V _{DD} |
| 6 | 4 | — | — | — | — | — | V _{DDA} | V _{REFH} |
| 7 | 5 | — | — | — | — | — | V _{SSA} | V _{REFL} |
| 8 | 6 | 4 | 4 | — | — | — | — | V _{SS} |
| 9 | 7 | 5 | 5 | PTB7 | — | — | SCL | EXTAL |
| 10 | 8 | 6 | 6 | PTB6 | — | — | SDA | XTAL |
| 11 | — | — | — | — | — | — | — | V _{SS} |
| 12 | 9 | 7 | 7 | PTB5 ¹ | — | FTM2CH5 | $\overline{SS0}$ | — |
| 13 | 10 | 8 | 8 | PTB4 ¹ | — | FTM2CH4 | MISO0 | — |
| 14 | 11 | 9 | — | PTC3 | — | FTM2CH3 | ADP11 | TSI9 |
| 15 | 12 | 10 | — | PTC2 | — | FTM2CH2 | ADP10 | TSI8 |
| 16 | — | — | — | PTD7 | — | — | — | — |
| 17 | — | — | — | PTD6 | — | — | — | — |

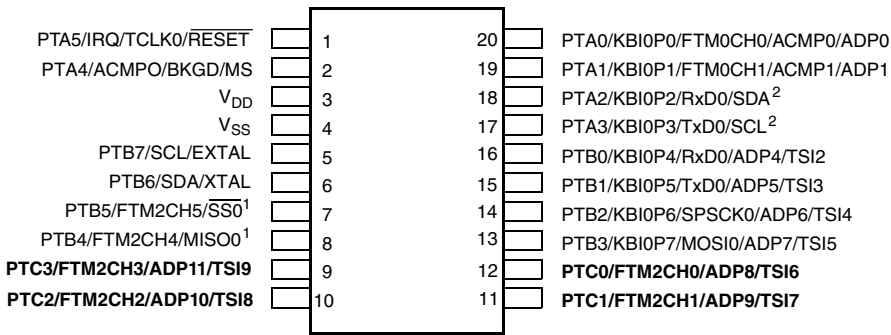
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Pins in **bold** are not available on less pin-count packages.

- 1. High source/sink current pins
- 2. True open drain pins

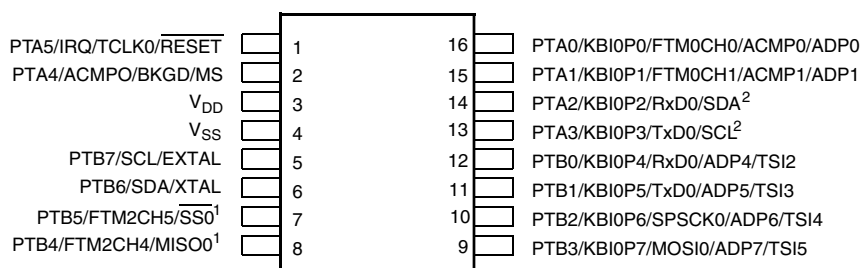
Figure 22. MC9S08PT16 32-pin LQFP package



Pins in **bold** are not available on less pin-count packages.

- 1. High source/sink current pins
- 2. True open drain pins

Figure 23. MC9S08PT16 20-pin SOIC and TSSOP package



Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins
2. True open drain pins

Figure 24. MC9S08PT16 16-pin TSSOP package

9 Revision history

The following table provides a revision history for this document.

Table 19. Revision history

| Rev. No. | Date | Substantial Changes |
|----------|---------|---|
| 1 | 7/2012 | Initial public release |
| 2 | 09/2014 | <ul style="list-style-type: none"> • Updated V_{OH} and V_{OL} in DC characteristics • Added footnote on the $S3I_{DD}$ in Supply current characteristics • Added EMC radiated emissions operating behaviors • Updated the typical of f_{int_t} to 31.25 kHz and updated footnote to $t_{Acquire}$ in External oscillator (XOSC) and ICS characteristics • Updated the assumption for all the timing values in SPI switching specifications • Updated the rating descriptions for t_{Rise} and t_{Fall} in Control timing • Updated the part number format to add new field for new part numbers in Fields |
| 3 | 06/2015 | <ul style="list-style-type: none"> • Corrected the Min. of the t_{extrst} in Control timing • Updated Thermal characteristics to add footnote to the T_A and removed redundant information. Updated the symbol of θ_{JA} to $R_{\theta JA}$. |